To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAF2011(L), HAF2011(S)

Silicon N Channel MOS FET Series
Power Switching

REJ03G1138-0500
Rev.5.00
Aug 21, 2007

Description

This FET has the over temperature shut-down capability sensing to the junction temperature.

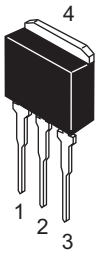
This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

Features

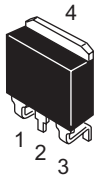
- Logic level operation (4 to 6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

Outline

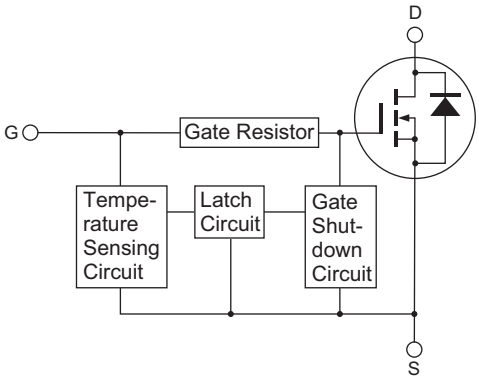
RENESAS Package code: PRSS0004AE-A
(Package name: LDPAK (L))



RENESAS Package code: PRSS0004AE-B
(Package name: LDPAK (S)-(1))



1. Gate
2. Drain
3. Source
4. Drain



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	60	V
Gate to source voltage	V_{GSS}	16	V
	V_{GSS}	–2.5	V
Drain current	I_D	40	A
Drain peak current	$I_{D\ (pulse)}$ Note 1	80	A
Body-drain diode reverse drain current	I_{DR}	40	A
Channel dissipation	Pch Note 2	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW ≤ 10 µs, duty cycle ≤ 1%
2. Value at Tc = 25°C

Typical Operation Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input voltage	V_{IH}	3.5	—	—	V	
	V_{IL}	—	—	1.2	V	
Input current (Gate non shut down)	I_{IH1}	—	—	100	µA	Vi = 8 V, V_{DS} = 0
	I_{IH2}	—	—	50	µA	Vi = 3.5 V, V_{DS} = 0
	I_{IL}	—	—	1	µA	Vi = 1.2 V, V_{DS} = 0
Input current (Gate shut down)	$I_{IH\ (sd)\ 1}$	—	0.8	—	mA	Vi = 8 V, V_{DS} = 0
	$I_{IH\ (sd)\ 2}$	—	0.35	—	mA	Vi = 3.5 V, V_{DS} = 0
Shut down temperature	Tsd	—	175	—	°C	Channel temperature
Gate operation voltage	V_{OP}	3.5	—	12	V	

Electrical Characteristics

(Ta = 25°C)

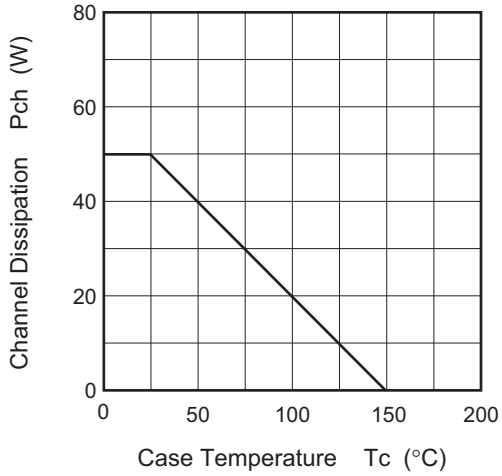
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain current	I_{D1}	15	—	—	A	V_{GS} = 3.5 V, V_{DS} = 2 V
	I_{D2}	—	—	10	mA	V_{GS} = 1.2 V, V_{DS} = 2 V
Drain to source breakdown voltage	$V_{(BR)\ DSS}$	60	—	—	V	I_D = 10 mA, V_{GS} = 0
Gate to source breakdown voltage	$V_{(BR)\ GSS}$	16	—	—	V	I_G = 300 µA, V_{DS} = 0
	$V_{(BR)\ GSS}$	–2.5	—	—	V	I_G = –100 µA, V_{DS} = 0
Gate to source leak current	I_{GSS1}	—	—	100	µA	V_{GS} = 8 V, V_{DS} = 0
	I_{GSS2}	—	—	50	µA	V_{GS} = 3.5 V, V_{DS} = 0
	I_{GSS3}	—	—	1	µA	V_{GS} = 1.2 V, V_{DS} = 0
	I_{GSS4}	—	—	–100	µA	V_{GS} = –2.4 V, V_{DS} = 0
Input current (shut down)	$I_{GS\ (op)\ 1}$	—	0.8	—	mA	V_{GS} = 8 V, V_{DS} = 0
	$I_{GS\ (op)\ 2}$	—	0.35	—	mA	V_{GS} = 3.5 V, V_{DS} = 0
Zero gate voltage drain current	I_{DSS}	—	—	10	µA	V_{DS} = 60 V, V_{GS} = 0
Gate to source cutoff voltage	$V_{GS\ (off)}$	1.0	—	2.25	V	I_D = 1 mA, V_{DS} = 10 V
Static drain to source on state resistance	$R_{DS\ (on)}$	—	25	33	mΩ	I_D = 20 A, V_{GS} = 4 V Note 3
	$R_{DS\ (on)}$	—	15	20	mΩ	I_D = 20 A, V_{GS} = 10 V Note 3
Forward transfer admittance	$\|y_{fs}\|$	8	16	—	S	I_D = 20 A, V_{DS} = 10 V Note 3
Output capacitance	Coss	—	940	—	pF	V_{DS} = 10 V, V_{GS} = 0 f = 1 MHz
Turn-on delay time	$t_{d\ (on)}$	—	10.7	—	µs	I_D = 20 A V_{GS} = 5 V R_L = 1.5 Ω
Rise time	t_r	—	66	—	µs	
Turn-off delay time	$t_{d\ (off)}$	—	15.5	—	µs	
Fall time	t_f	—	19	—	µs	
Body-drain diode forward voltage	V_{DF}	—	1	—	V	I_F = 40 A, V_{GS} = 0
Body-drain diode reverse recovery time	t_{rr}	—	200	—	ns	I_F = 40 A, V_{GS} = 0 di_F/dt = 50 A/µs
Over load shut down operation time Note4	t_{os1}	—	1	—	ms	V_{GS} = 5 V, V_{DD} = 16 V

Notes: 3. Pulse test

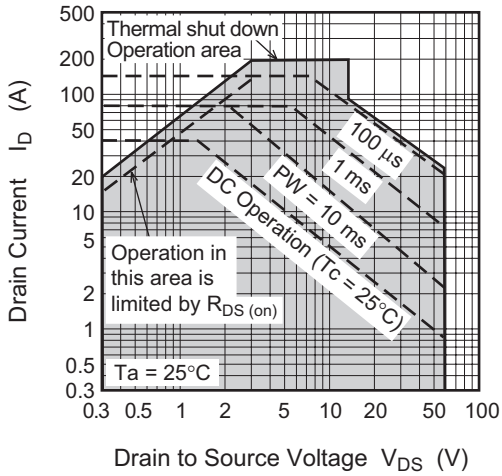
4. Including the junction temperature rise of the over loaded condition.

Main Characteristics

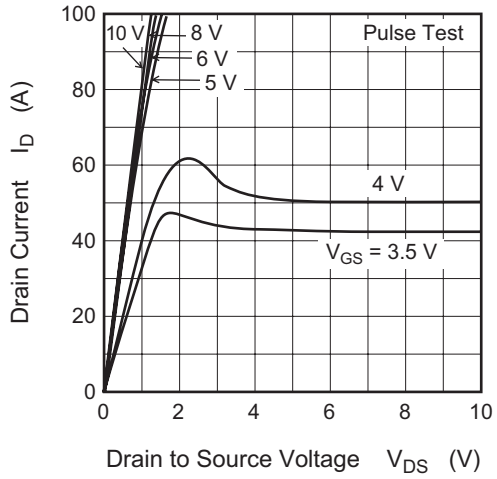
Power vs. Temperature Derating



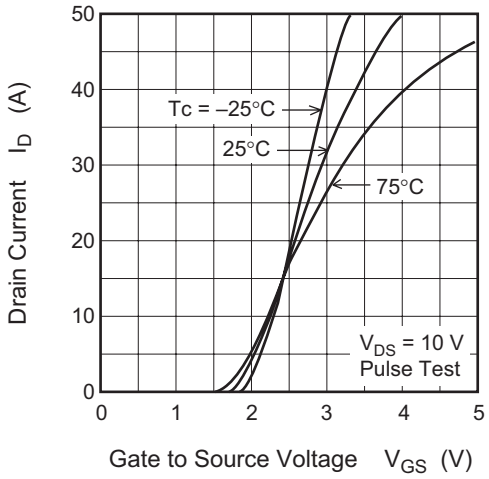
Maximum Safe Operation Area



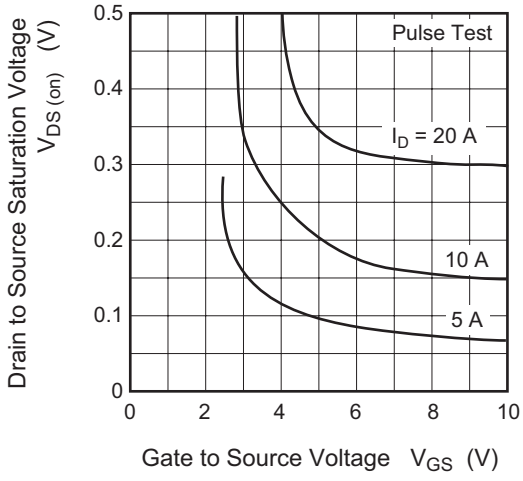
Typical Output Characteristics



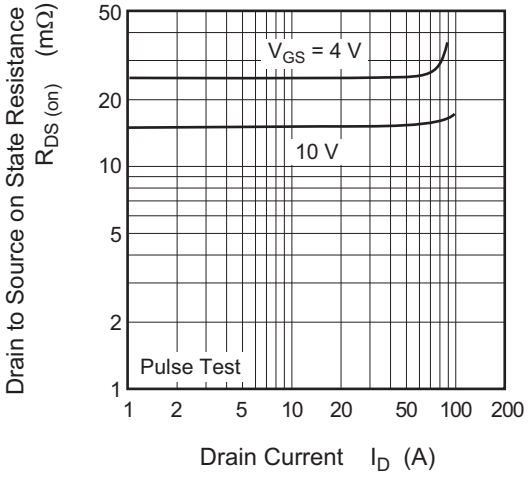
Typical Transfer Characteristics



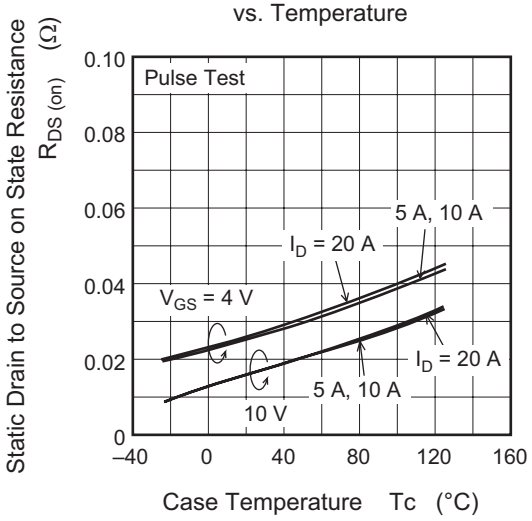
Drain to Source Saturation Voltage vs.
Gate to Source Voltage



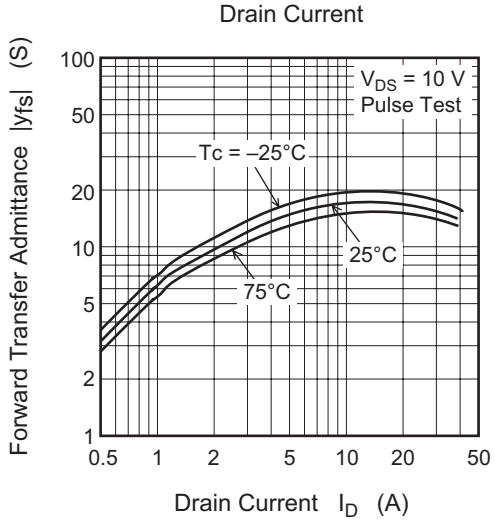
Static Drain to Source on State Resistance
vs. Drain Current



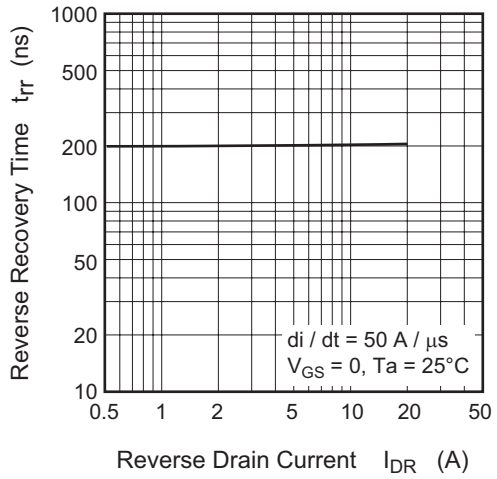
Static Drain to Source on State Resistance vs. Temperature



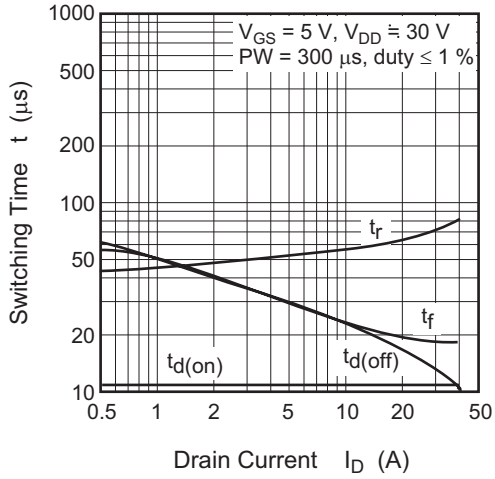
Forward Transfer Admittance vs. Drain Current



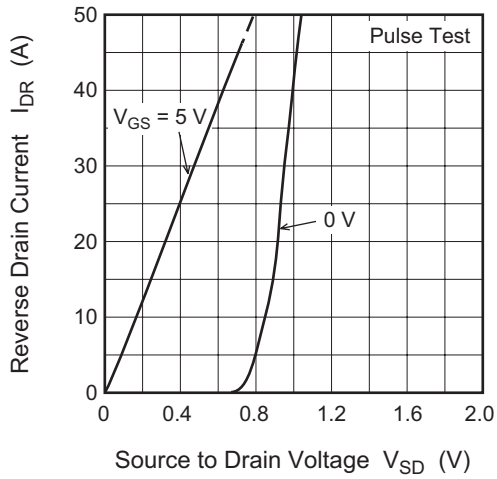
Body-Drain Diode Reverse Recovery Time



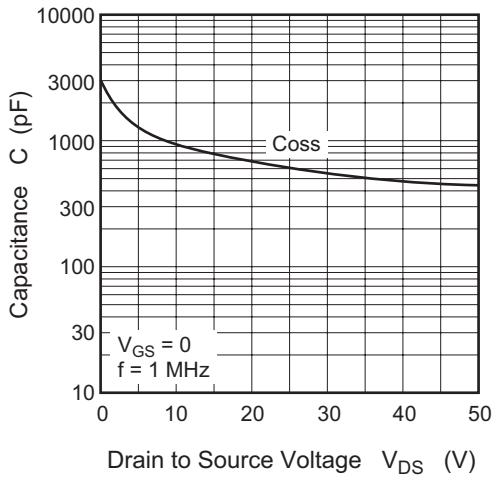
Switching Characteristics



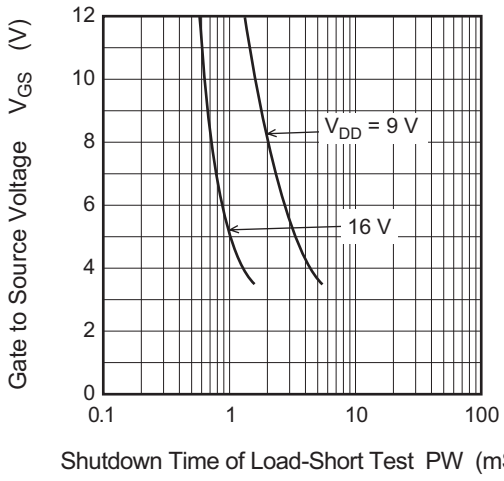
Reverse Drain Current vs. Source to Drain Voltage



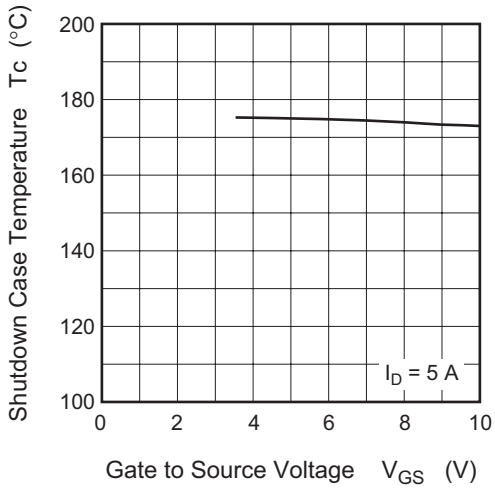
Typical Capacitance vs. Drain to Source Voltage



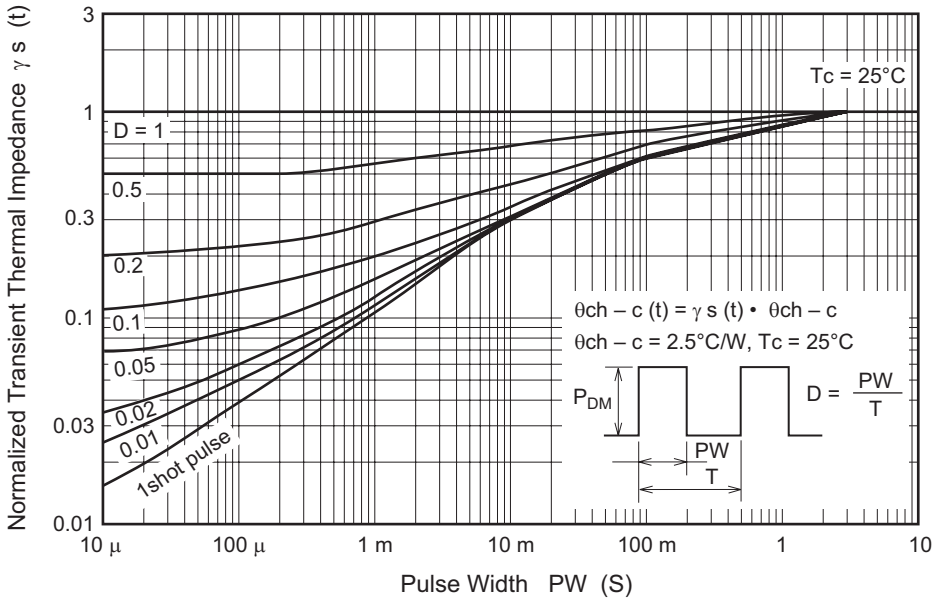
Gate to Source Voltage vs.
Shutdown Time of Load-Short Test



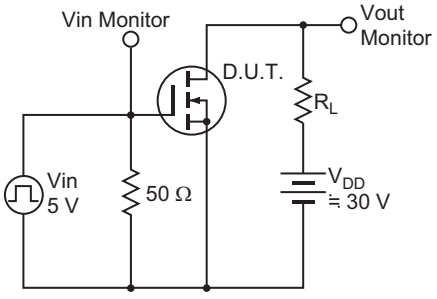
Shutdown Case Temperature vs.
Gate to Source Voltage



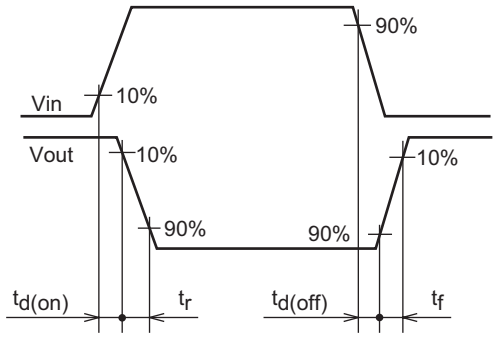
Normalized Transient Thermal Impedance vs. Pulse Width



Switching Time Test Circuit



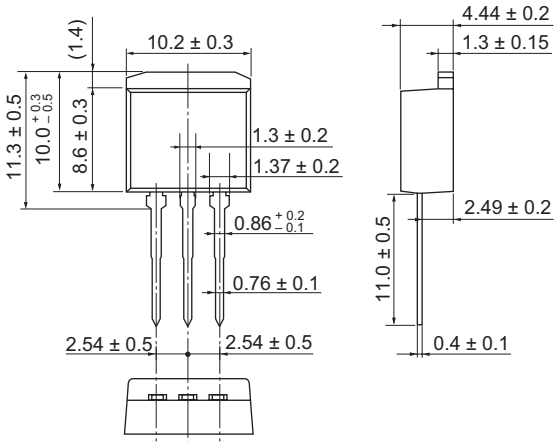
Waveform



Package Dimensions

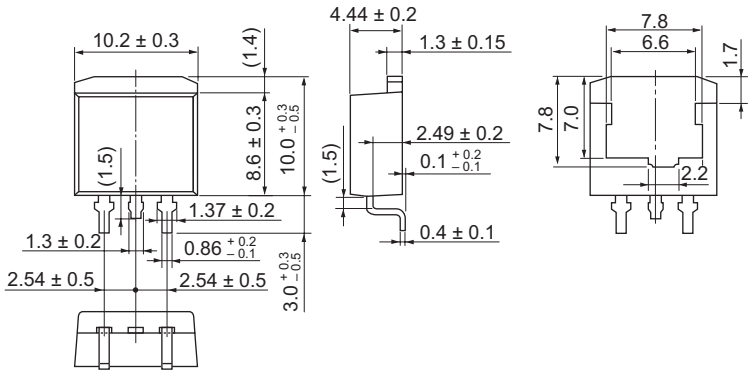
Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
LDPAK(L)	—	PRSS0004AE-A	LDPAK(L) / LDPAK(L)V	1.40g

Unit: mm



Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
LDPAK(S)-(1)	SC-83	PRSS0004AE-B	LDPAK(S)-(1) / LDPAK(S)-(1)V	1.30g

Unit: mm



Ordering Information

Part No.	Quantity	Shipping Container
HAF2011-90L	Max: 50 pcs/sack	Sack
HAF2011-90S	Max: 50 pcs/sack	Sack
HAF2011-90STL	1000 pcs/Reel	Embossed tape
HAF2011-90STR	1000 pcs/Reel	Embossed tape

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

RENESAS SALES OFFICES

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Renesas Technology America, Inc.
450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd.
10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.
Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510

Colophon .7.0